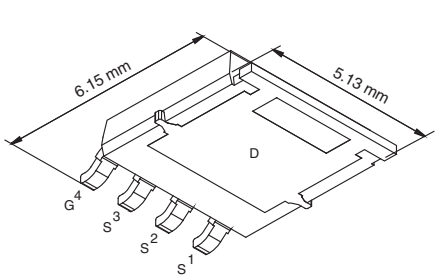
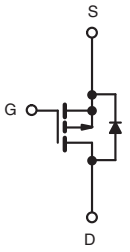
Automotive
P-Channel 80 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	- 80
$R_{DS(on)}$ (Ω) at V_{GS} = - 10 V	0.025
$R_{DS(on)}$ (Ω) at V_{GS} = - 6 V	0.029
I_D (A)	- 32
Configuration	Single

PowerPAK® SO-8L Single





P-Channel MOSFET

FEATURES

- **Halogen-free According to IEC 61249-2-21 Definition**
- TrenchFET® Power MOSFET
- Compliant to RoHS Directive 2002/95/EC
- AEC-Q101 Qualified[d]
- Find out more about Vishay's Automotive Grade Product Requirements at: www.vishay.com/applications

AUTOMOTIVE GRADE

Pb-free

RoHS COMPLIANT

HALOGEN FREE

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and Halogen-free	SQJ469EP-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	- 80	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current[a]	T_C = 25 °C	I_D	- 32	A
	T_C = 125 °C		- 24	
Continuous Source Current (Diode Conduction)[a]		I_S	- 32	
Pulsed Drain Current[b]		I_{DM}	- 128	
Single Pulse Avalanche Current	L = 0.1 mH	I_{AS}	- 45	
Single Pulse Avalanche Energy		E_{AS}	101	mJ
Maximum Power Dissipation[b]	T_C = 25 °C	P_D	100	W
	T_C = 125 °C		33	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to + 175	°C
Soldering Recommendations (Peak Temperature)[e, f]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount[c]	R_{thJA}	65	°C/W
Junction-to-Case (Drain)		R_{thJC}	1.5	

Notes

a. Package limited.
b. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
c. When mounted on 1" square PCB (FR4 material).
d. Parametric verification ongoing.
e. See solder profile (www.vishay.com/ppg?73257). The PowerPAK SO-8L. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

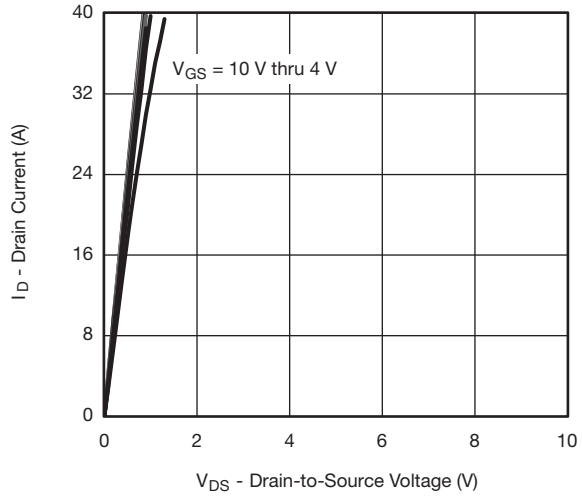
SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = - 250 µA		- 80	-	-	V
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = - 250 µA		- 1.5	- 2.0	- 2.5	
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{GS} = 0 V	V_{DS} = - 80 V	-	-	- 1	µA
		V_{GS} = 0 V	V_{DS} = - 80 V, T_J = 125 °C	-	-	- 50	
		V_{GS} = 0 V	V_{DS} = - 80 V, T_J = 175 °C	-	-	- 150	
On-State Drain Current[a]	$I_{D(on)}$	V_{GS} = - 10 V	V_{DS} = -5 V	- 30	-	-	A
Drain-Source On-State Resistance[a]	$R_{DS(on)}$	V_{GS} = - 10 V	I_D = - 10.2 A	-	0.021	0.025	Ω
		V_{GS} = - 10 V	T_J = 125 °C	-	0.036	0.043	
		V_{GS} = - 10 V	T_J = 175 °C	-	0.045	0.054	
		V_{GS} = - 6 V	I_D = - 8.1 A	-	0.024	0.029	
Forward Transconductance[b]	g_{fs}	V_{DS} = - 15 V, I_D = - 10.2 A		-	35	-	S
Dynamic[b]							
Input Capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = - 40 V, f = 1 MHz	-	4250	5100	pF
Output Capacitance	C_{oss}			-	250	300	
Reverse Transfer Capacitance	C_{rss}			-	215	260	
Total Gate Charge[c]	Q_g	V_{GS} = - 10 V	V_{DS} = - 40 V, I_D = - 10.2 A	-	101	155	nC
Gate-Source Charge[c]	Q_{gs}			-	13	-	
Gate-Drain Charge[c]	Q_{gd}			-	21	-	
Turn-On Delay Time[c]	$t_{d(on)}$	V_{DD} = - 40 V, R_L = 4.9 Ω $I_D \cong$ - 8.1 A, V_{GEN} = - 10 V, R_g = 1.0 Ω		-	16	20	ns
Rise Time[c]	t_r			-	16	20	
Turn-Off Delay Time[c]	$t_{d(off)}$			-	150	180	
Fall Time[c]	t_f			-	40	50	
Source-Drain Diode Ratings and Characteristics[b]							
Pulsed Current[a]	I_{SM}			-	-	- 128	A
Forward Voltage	V_{SD}	I_F = - 8.1 A, V_{GS} = 0 V		-	- 0.8	- 1.2	V

Notes

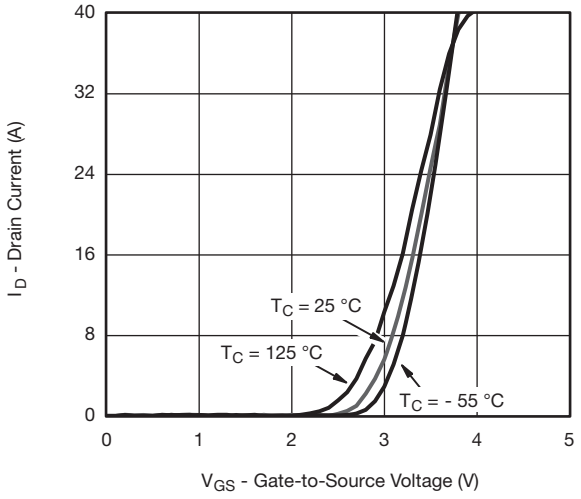
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

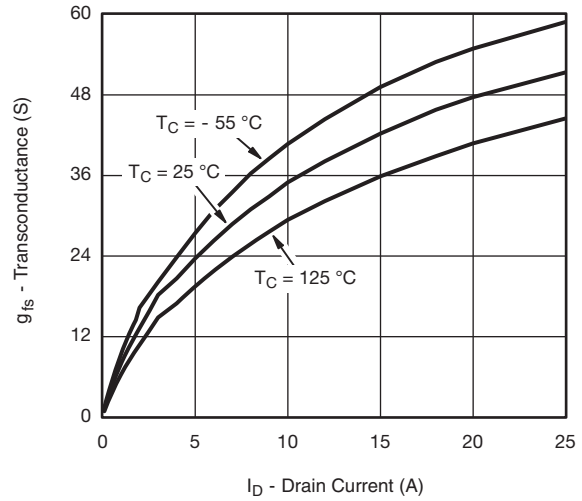
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



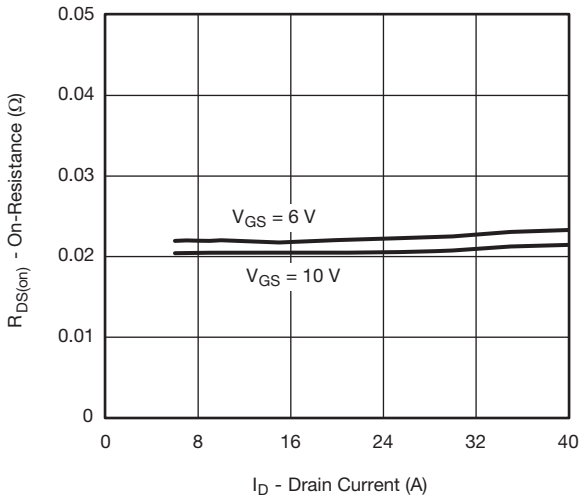
Output Characteristics



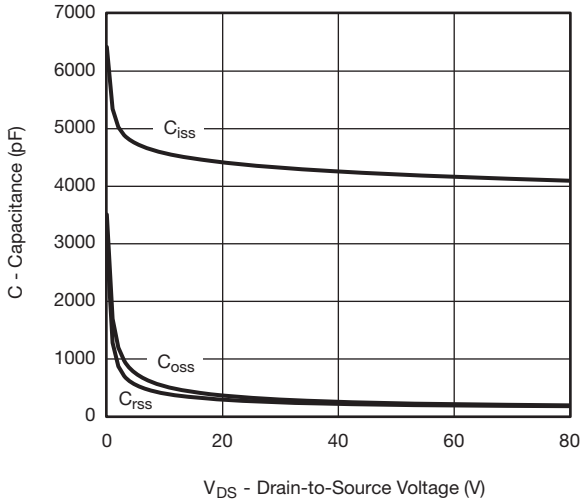
Transfer Characteristics



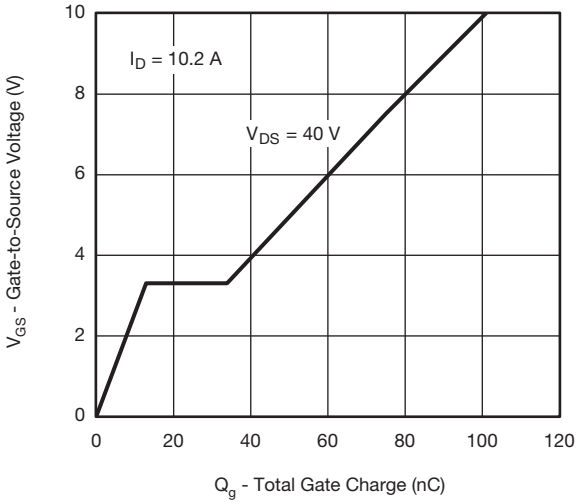
Transconductance



On-Resistance vs. Drain Current

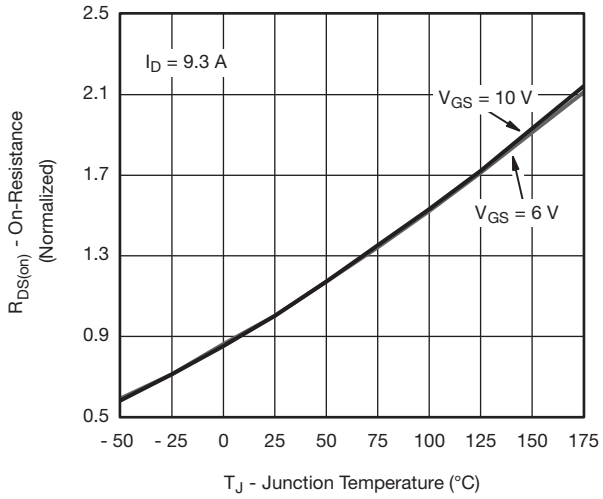


Capacitance

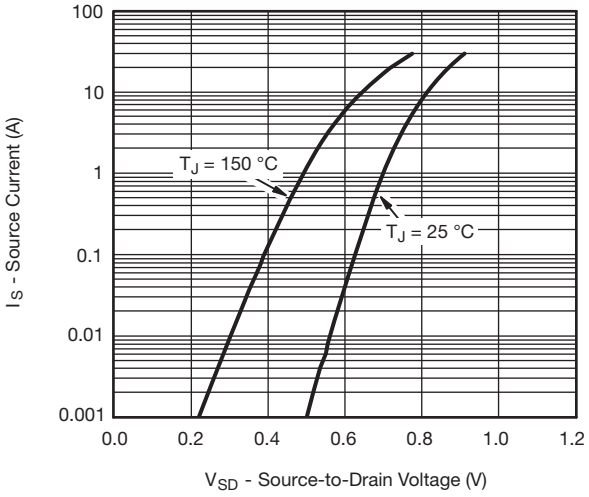


Gate Charge

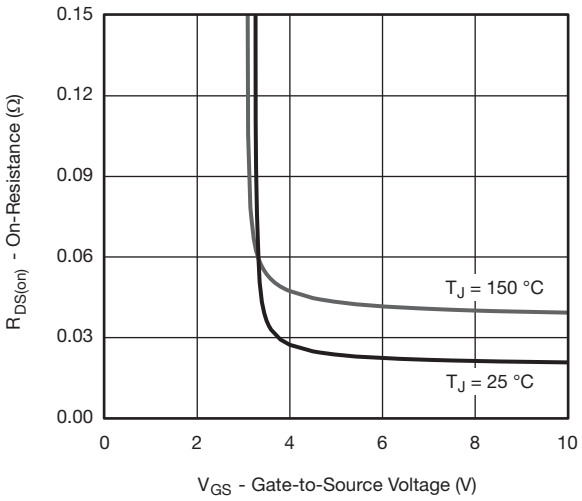
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



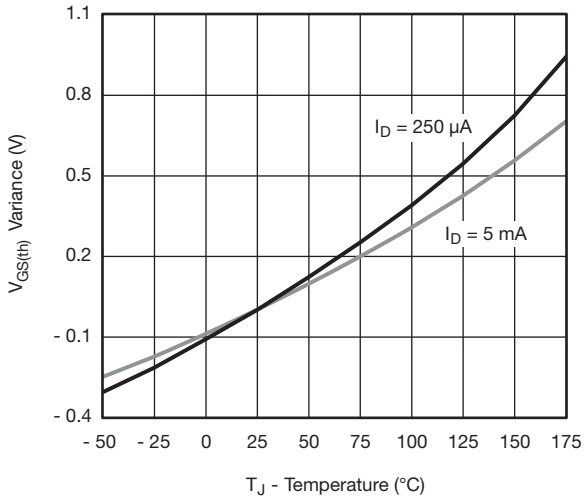
On-Resistance vs. Junction Temperature



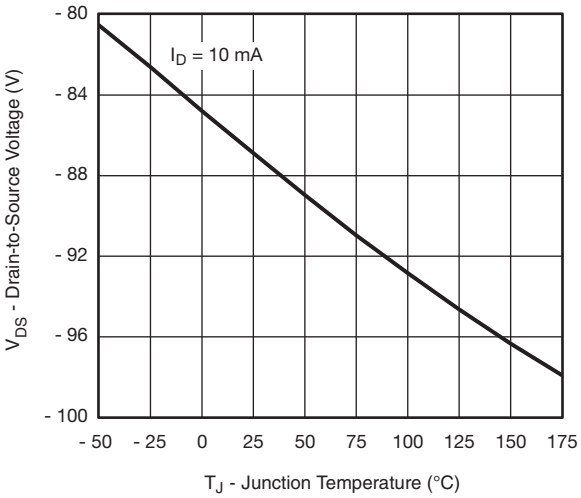
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

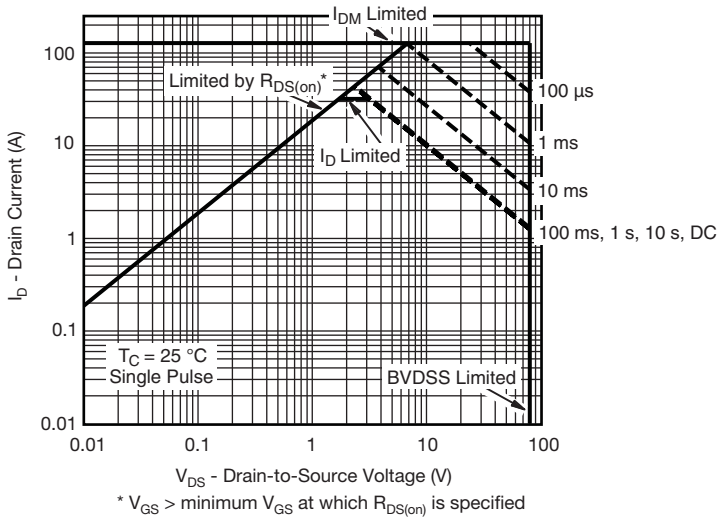


Threshold Voltage

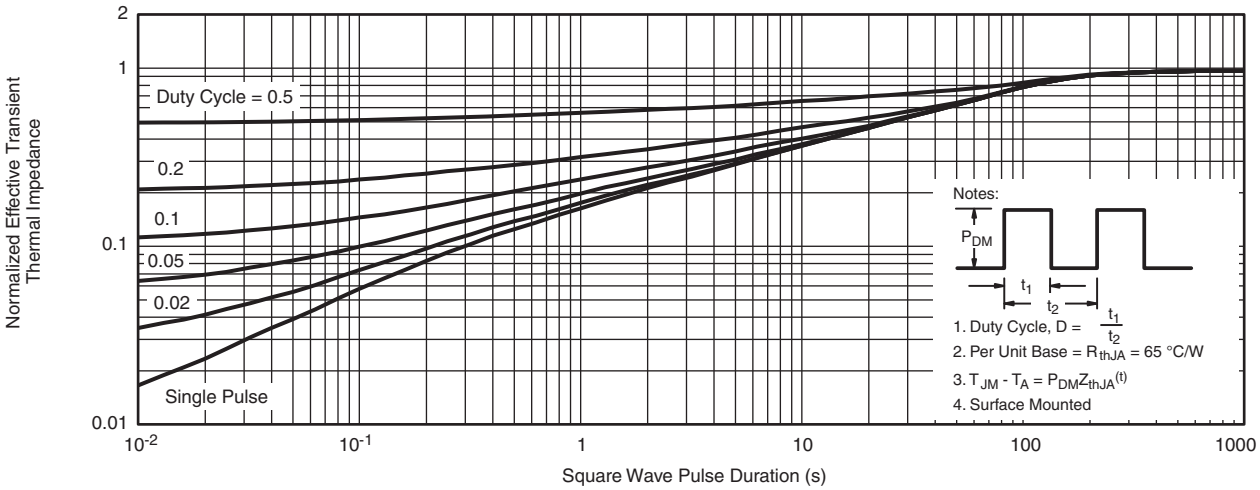


Drain-Source Breakdown vs. Junction Temperature

THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)

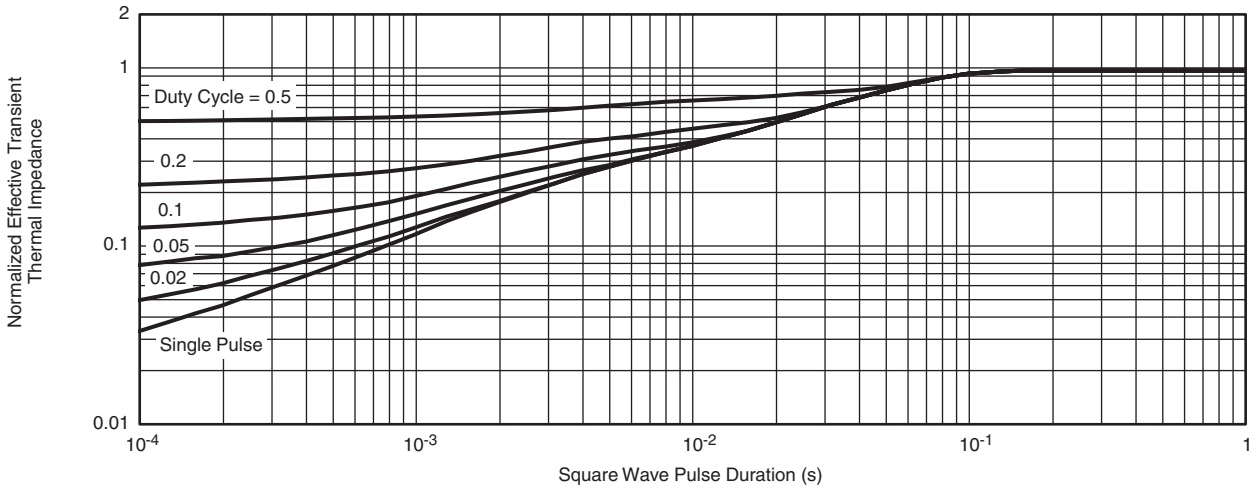


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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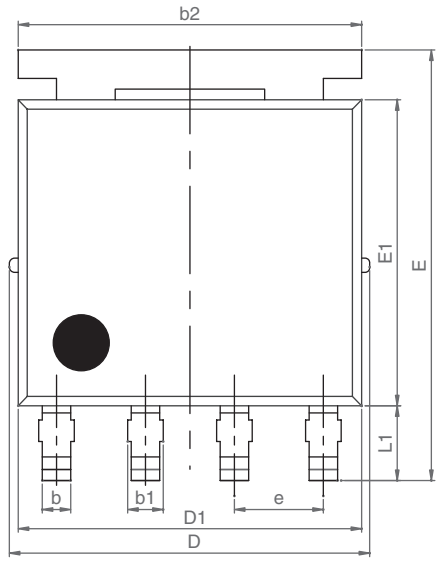
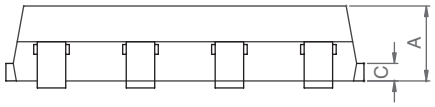
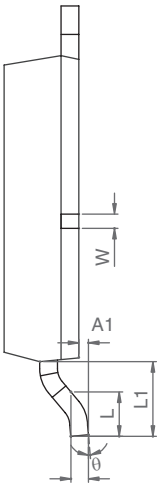
PowerPAK® SO-8L CASE OUTLINE

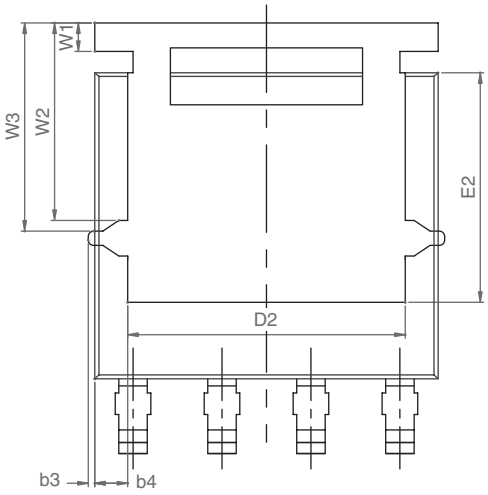


TOPSIDE VIEW

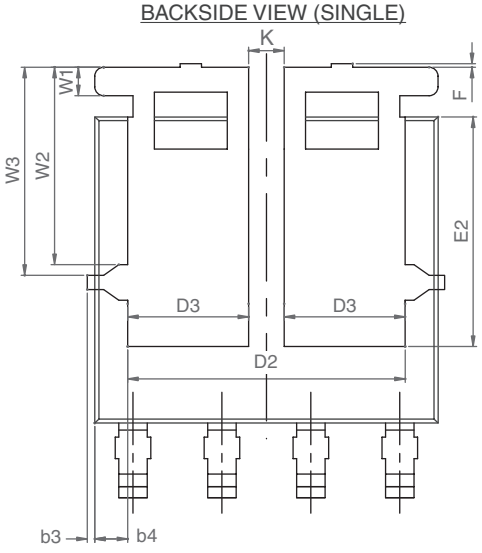




0.25 Gauge Line



BACKSIDE VIEW (SINGLE)



BACKSIDE VIEW (DUAL)

DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	1.00	1.07	1.14	0.039	0.042	0.045
A1	0.00	-	0.127	0.00	-	0.005
b	0.33	0.41	0.48	0.013	0.016	0.019
b1	0.44	0.51	0.58	0.017	0.020	0.023
b2	4.80	4.90	5.00	0.189	0.193	0.197
b3		0.094			0.004	
b4		0.47			0.019	
c	0.20	0.25	0.30	0.008	0.010	0.012
D	5.00	5.13	5.25	0.197	0.202	0.207
D1	4.80	4.90	5.00	0.189	0.193	0.197
D2	3.86	3.96	4.06	0.152	0.156	0.160
D3	1.63	1.73	1.83	0.064	0.068	0.072
e		1.27 BSC			0.050 BSC	
E	6.05	6.15	6.25	0.238	0.242	0.246
E1	4.27	4.37	4.47	0.168	0.172	0.176
E2	3.18	3.28	3.38	0.125	0.129	0.133
F	-	-	0.15	-	-	0.006
L	0.62	0.72	0.82	0.024	0.028	0.032
L1	0.92	1.07	1.22	0.036	0.042	0.048
K		0.51			0.020	
W		0.23			0.009	
W1		0.41			0.016	
W2		2.82			0.111	
W3		2.96			0.117	
θ	0°	-	10°	0°	-	10°

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DWG: 5976

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